

1N4001G THRU 1N4007G

TECHNICAL SPECIFICATIONS OF SILICON RECTIFIER

VOLTAGE: 50-1000V

CURRENT: 1.0A

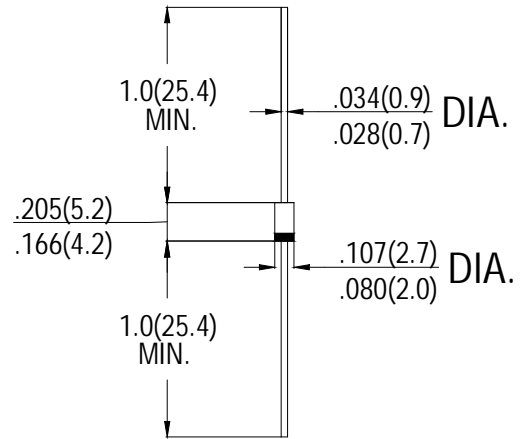
FEATURES

- High reliability
- Low leakage
- Low forward voltage drop
- High current capability

MECHANICAL DATA

- **Case:** Molded plastic
- **Epoxy:** UL94V-0 rate flame retardant
- **Lead:** MIL-STD- 202E, Method 208 guaranteed
- **Polarity:** Color band denotes cathode end
- **Mounting position:** Any
- **Weight:** 0.33 grams

DO-41



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave, 60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

	SYMBOL	1N4001G	1N4002G	1N4003G	1N4004G	1N4005G	1N4006G	1N4007G	units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward rectified Current at $T_A=75^\circ\text{C}$	I_o	1.0							A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I_{FSM}	30							A
Maximum Instantaneous forward Voltage at 1.0A DC	V_F	1.1							V
Maximum DC Reverse Current at Rated DC Blocking Voltage	@ $T_A=25^\circ\text{C}$	5.0							μA
	@ $T_A=100^\circ\text{C}$	500							
Maximum Full Load Reverse Current Average Full Cycle .375"(9.5mm) lead length at $T_L=75^\circ\text{C}$	I_R	30							
Typical Junction Capacitance (Note)	C_J	15							pF
Typical Thermal Resistance	$R_{\theta JA}$	50							$^\circ\text{C/W}$

Notes: Measured at 1MHz and applied reverse voltage of 4.0 volts